MCP601/2/3/4

2.7V to 5.5V Single-Supply CMOS Op Amps

Features

· Single-Supply: 2.7V to 5.5V

· Rail-to-Rail Output

· Input Range Includes Ground

Gain Bandwidth Product: 2.8 MHz (typ.)

· Unity-Gain Stable

Low Quiescent Current: 230 μA/amplifier (typ.)

Chip Select (CS): MCP603 only

· Temperature Ranges:

Industrial: -40°C to +85°C
 Extended: -40°C to +125°C
 Available in Single, Dual and Quad

Typical Applications

- · Portable Equipment
- · A/D Converter Driver
- · Photo Diode Pre-amp
- · Analog Filters
- Data Acquisition
- · Notebooks and PDAs
- Sensor Interface

Available Tools

- · SPICE Macro Models at www.microchip.com
- FilterLab[®] Software at www.microchip.com

Description

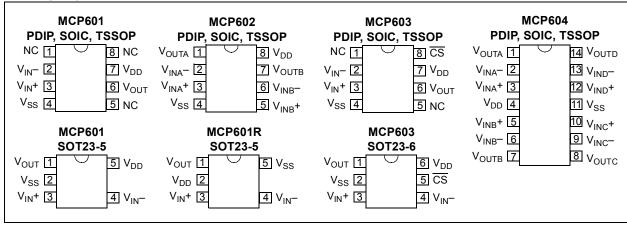
The Microchip Technology Inc. MCP601/2/3/4 family of low-power operational amplifiers (op amps) are offered in single (MCP601), single with Chip Select ($\overline{\text{CS}}$) (MCP603), dual (MCP602) and quad (MCP604) configurations. These op amps utilize an advanced CMOS technology that provides low bias current, high-speed operation, high open-loop gain and rail-to-rail output swing. This product offering operates with a single supply voltage that can be as low as 2.7V, while drawing 230 μ A (typ.) of quiescent current per amplifier. In addition, the common mode input voltage range goes 0.3V below ground, making these amplifiers ideal for single-supply operation.

These devices are appropriate for low-power, batteryoperated circuits due to the low quiescent current, for A/D convert driver amplifiers because of their wide bandwidth or for anti-aliasing filters by virtue of their low input bias current.

The MCP601, MCP602 and MCP603 are available in standard 8-lead PDIP, SOIC and TSSOP packages. The MCP601 and MCP601R are also available in a standard 5-lead SOT-23 package, while the MCP603 is available in a standard 6-lead SOT-23 package. The MCP604 is offered in standard 14-lead PDIP, SOIC and TSSOP packages.

The MCP601/2/3/4 family is available in the Industrial and Extended temperature ranges and has a power supply range of 2.7V to 5.5V.

Package Types



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

V _{DD} - V _{SS}	7.0V
All inputs and outputs	V_{SS} - 0.3V to V_{DD} + 0.3V
Difference Input voltage	V _{DD} - V _{SS}
Output Short Circuit Current	continuous
Current at Input Pin	±2 mA
Current at Output and Supply Pins .	±30 mA
Storage temperature	65°C to +150°C
Junction temperature	+150°C
ESD protection on all pins (HBM; M	M) ≥ 3 kV; 200V

† Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

PIN FUNCTION TABLE

Name	Function
V _{IN} +, V _{INA} +, V _{INB} +, V _{INC} +, V _{IND} +	Non-inverting Inputs
V _{IN} -, V _{INA} -, V _{INB} -, V _{INC} -, V _{IND} -	Inverting Inputs
V_{DD}	Positive Power Supply
V _{SS}	Negative Power Supply
V _{OUT} , V _{OUTA} , V _{OUTB} , V _{OUTC} , V _{OUTD}	Outputs
CS	Chip Select
NC	No Internal Connection

DC CHARACTERISTICS

DC CHARACTERISTIC						
Electrical Specifications: Unless		pecified, T _A	= +25°C	$V_{DD} = +2.7$	7V to +5	$1.5V$, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$,
$V_{OUT} \approx V_{DD}/2$ and $R_L = 100 \text{ k}\Omega$ to	V _{DD} /2.			· ·		
Parameters	Sym	Min	Тур	Max	Units	Conditions
Input Offset						
Input Offset Voltage	Vos	-2	±0.7	+2	mV	
Industrial Temperature	Vos	-3	±1	+3	mV	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C \text{ (Note 1)}$
Extended Temperature	Vos	-4.5	±1	+4.5	mV	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C \text{ (Note 1)}$
Input Offset Temperature Drift	$\Delta V_{OS}/\Delta T_{A}$	_	±2.5	_	μV/°C	T _A = -40°C to +125°C
Power Supply Rejection	PSRR	80	88	_	dB	V _{DD} = 2.7V to 5.5V
Input Current and Impedance						
Input Bias Current	I_{B}	_	1	-	pА	
Industrial Temperature	Ι _Β	_	20	60	pА	T _A = +85°C (Note 1)
Extended Temperature	I _B	_	450	5000	pА	T _A = +125°C (Note 1)
Input Offset Current	Ios	_	±1	_	pА	
Common Mode Input Impedance	Z _{CM}	_	10 ¹³ 6	_	ΩpF	
Differential Input Impedance	Z _{DIFF}	_	10 ¹³ 3	_	ΩpF	
Common Mode						
Common Mode Input Range	V_{CMR}	$V_{SS} - 0.3$		V _{DD} – 1.2	>	
Common Mode Rejection Ratio	CMRR	75	90		dB	$V_{DD} = 5.0V$, $V_{CM} = -0.3V$ to 3.8V
Open-loop Gain						
DC Open-loop Gain (large signal)	A _{OL}	100	115	1	dB	R_L = 25 k Ω to $V_{DD}/2$, V_{OUT} = 100 mV to V_{DD} – 100 mV
	A _{OL}	95	110	_	dB	R_L = 5 k Ω to $V_{DD}/2$, V_{OUT} = 100 mV to V_{DD} – 100 mV
Output						
Maximum Output Voltage Swing	V_{OL}, V_{OH}	V _{SS} + 15	_	V _{DD} – 20	mV	$R_L = 25 \text{ k}\Omega \text{ to } V_{DD}/2, \text{ Output overdrive} = 0.5$
	V _{OL} , V _{OH}	V _{SS} + 45	_	V _{DD} – 60	mV	$R_L = 5 \text{ k}\Omega \text{ to } V_{DD}/2$, Output overdrive = 0.5V
Linear Output Voltage Swing	V _{OUT}	V _{SS} + 100	_	V _{DD} – 100	mV	R_L = 25 k Ω to $V_{DD}/2$, $A_{OL} \ge 100 \text{ dB}$
	V _{OUT}	V _{SS} + 100	-	V _{DD} – 100	mV	$R_L = 5 \text{ k}\Omega \text{ to } V_{DD}/2, A_{OL} \ge 95 \text{ dB}$
Output Short Circuit Current	I _{SC}	_	±22	_	mA	V _{DD} = 5.5V
	I _{SC}	_	±12	_	mA	V _{DD} = 2.7V
Power Supply						
Supply Voltage	V_{DD}	2.7	_	5.5	V	
Quiescent Current per Amplifier	IQ	_	230	325	μΑ	I _O = 0
						-

Note 1: These specifications are not tested in either the SOT-23 or TSSOP packages with date codes older than YYWW = 0408. In these cases, the minimum and maximum values are by design and characterization only.

AC CHARACTERISTICS

Parameters	Sym	Min	Тур	Max	Units	Conditions
Frequency Response						
Gain Bandwidth Product	GBWP	_	2.8	_	MHz	
Phase Margin	PM	_	50	_	0	G = +1 V/V
Step Response	•		•		•	
Slew Rate	SR	_	2.3	_	V/µs	G = +1 V/V
Settling Time (0.01%)	t _{settle}	_	4.5	_	μs	G = +1 V/V, 3.8V step
Noise						
Input Noise Voltage	E _{ni}	_	7	_	μV _{P-P}	f = 0.1 Hz to 10 Hz
nput Noise Voltage Density	e _{ni}	_	29	_	nV/√Hz	f = 1 kHz
	e _{ni}	_	21	_	nV/√Hz	f = 10 kHz
Input Noise Current Density	i _{ni}	_	0.6	_	fA/√Hz	f = 1 kHz

MCP603 CHIP SELECT CHARACTERISTICS

Electrical Specifications: Unless otherwise indicated, $T_A = +25$ °C, $V_{DD} = +2.7$ V to +5.5V, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 100$ kΩ to $V_{DD}/2$ and $C_L = 50$ pF.										
Parameters	Sym	Min	Тур	Max	Units	Conditions				
DC Characteristics										
CS Logic Threshold, Low	V _{IL}	V _{SS}	_	0.2 V _{DD}	V					
CS Input Current, Low	I _{CSL}	-1.0	_	_	μΑ	<u>CS</u> = 0.2V _{DD}				
CS Logic Threshold, High	V _{IH}	0.8 V _{DD}	_	V_{DD}	V					
CS Input Current, High	I _{CSH}	_	0.7	2.0	μA	CS = V _{DD}				
Shutdown V _{SS} current	I _{Q_SHDN}	-2.0	-0.7	_	μΑ	CS = V _{DD}				
Amplifier Output Leakage in Shutdown	I _{O_SHDN}	_	1	_	nA					
CS Threshold Hysteresis	HYST	_	0.3	_	V	Internal switch				
Timing										
CS Low to Amplifier Output Turn-on Time	t _{ON}	_	3.1	10	μs	<u>CS</u> ≤ 0.2V _{DD} , G = +1 V/V				
CS High to Amplifier Output High-Z Time	toff	_	100	_	ns	$\overline{\text{CS}} \ge 0.8 \text{V}_{\text{DD}}, \text{ G} = +1 \text{ V/V}, \text{ No load}.$				

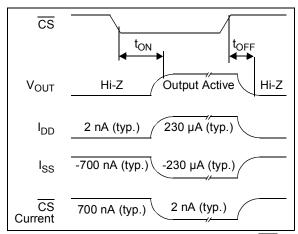


FIGURE 1-1: MCP603 Chip Select (\overline{CS}) Timing Diagram.

MCP601/2/3/4

TEMPERATURE CHARACTERISTICS

Electrical Specifications: Unless	otherwise	e indicate	ed, V _{DD}	= +2.7V 1	to +5.5V	and V _{SS} = GND.
Parameters	Sym	Min	Тур	Max	Units	Conditions
Temperature Ranges						
Specified Temperature Range	T _A	-40	_	+85	°C	Industrial temperature parts
	T _A	-40	_	+125	°C	Extended temperature parts
Operating Temperature Range	T _A	-40	_	+125	°C	Note
Storage Temperature Range	T _A	-65	_	+150	°C	
Thermal Package Resistances						
Thermal Resistance, 5L-SOT23	θ_{JA}	_	256	_	°C/W	
Thermal Resistance, 6L-SOT23	θ_{JA}	_	230	_	°C/W	
Thermal Resistance, 8L-PDIP	θ_{JA}	_	85	_	°C/W	
Thermal Resistance, 8L-SOIC	θ_{JA}	_	163	_	°C/W	
Thermal Resistance, 8L-TSSOP	θ_{JA}	_	124	_	°C/W	
Thermal Resistance, 14L-PDIP	θ_{JA}		70		°C/W	
Thermal Resistance, 14L-SOIC	θ_{JA}	_	120	_	°C/W	
Thermal Resistance, 14L-TSSOP	θ_{JA}	_	100	_	°C/W	

Note: The Industrial temperature parts operate over this extended range, but with reduced performance. The Extended temperature specs do not apply to Industrial temperature parts. In any case, the internal Junction temperature (T_J) must not exceed the absolute maximum specification of 150°C.

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

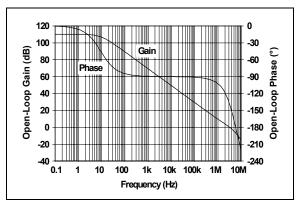


FIGURE 2-1: Open-Loop Gain, Phase vs. Frequency.

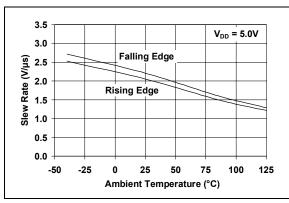


FIGURE 2-2: Slew Rate vs. Temperature.

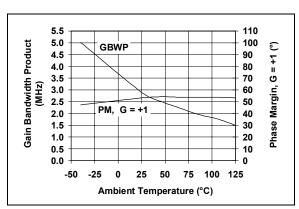


FIGURE 2-3: Gain Bandwidth Product, Phase Margin vs. Temperature.

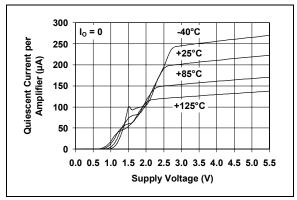


FIGURE 2-4: Quiescent Current vs. Supply Voltage.

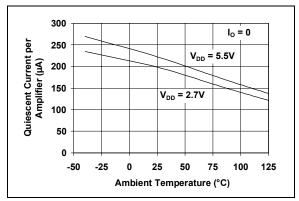


FIGURE 2-5: Quiescent Current vs. Temperature.

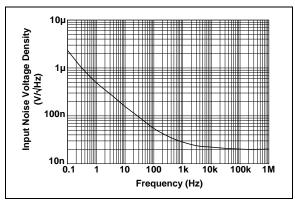


FIGURE 2-6: Input Noise Voltage Density vs. Frequency.

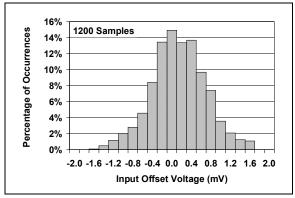


FIGURE 2-7: Input Offset Voltage.

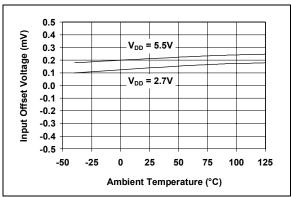


FIGURE 2-8: Input Offset Voltage vs. Temperature.

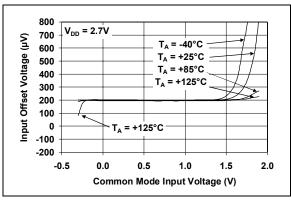


FIGURE 2-9: Input Offset Voltage vs. Common Mode Input Voltage with $V_{DD} = 2.7V$.

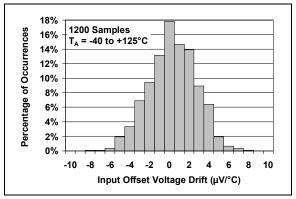


FIGURE 2-10: Input Offset Voltage Drift.

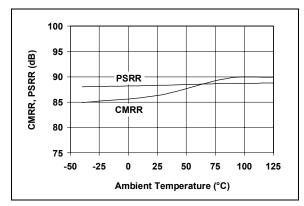


FIGURE 2-11: CMRR, PSRR vs. Temperature.

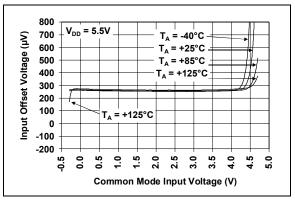


FIGURE 2-12: Input Offset Voltage vs. Common Mode Input Voltage with $V_{DD} = 5.5V$.

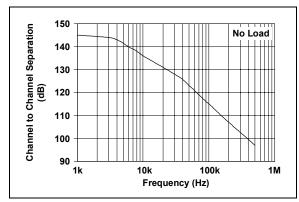


FIGURE 2-13: Channel-to-Channel Separation vs. Frequency.

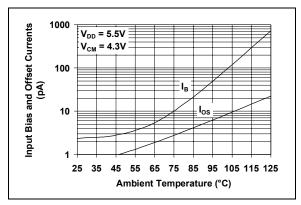


FIGURE 2-14: Input Bias Current, Input Offset Current vs. Ambient Temperature.

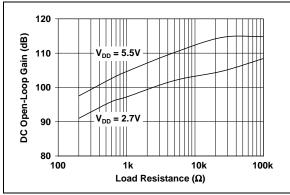


FIGURE 2-15: DC Open-Loop Gain vs. Load Resistance.

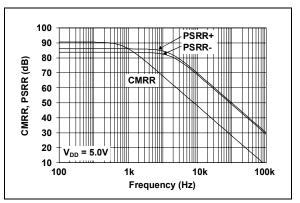


FIGURE 2-16: CMRR, PSRR vs. Frequency.

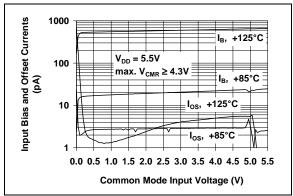


FIGURE 2-17: Input Bias Current, Input Offset Current vs. Common Mode Input Voltage.

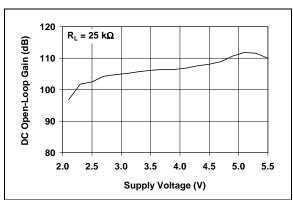


FIGURE 2-18: DC Open-Loop Gain vs. Supply Voltage.

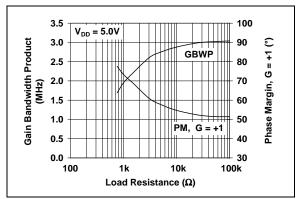


FIGURE 2-19: Gain Bandwidth Product, Phase Margin vs. Load Resistance.

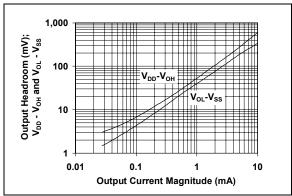


FIGURE 2-20: Output Voltage Headroom vs. Output Current.

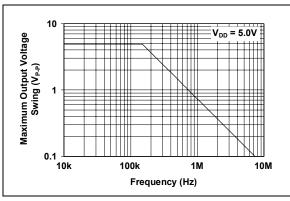


FIGURE 2-21: Maximum Output Voltage Swing vs. Frequency.

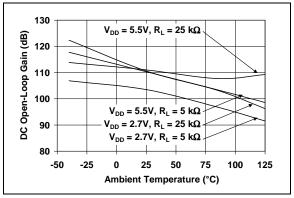


FIGURE 2-22: DC Open-Loop Gain vs. Temperature.

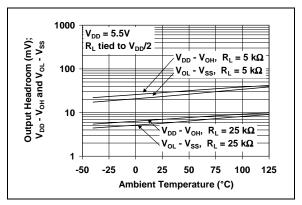


FIGURE 2-23: Output Voltage Headroom vs. Temperature.

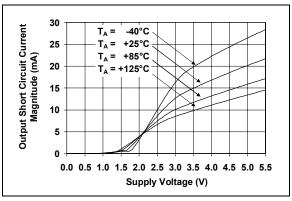


FIGURE 2-24: Output Short-Circuit Current vs. Supply Voltage.

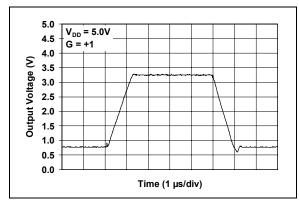


FIGURE 2-25: Large Signal Non-Inverting Pulse Response.

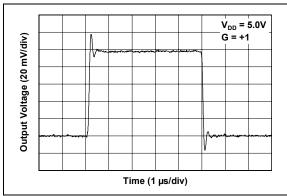


FIGURE 2-26: Small Signal Non-Inverting Pulse Response.

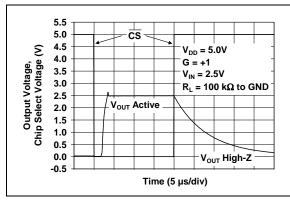


FIGURE 2-27: Chip Select Timing (MCP603).

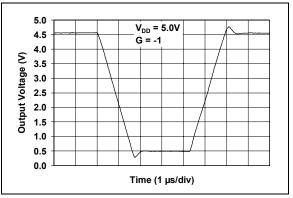


FIGURE 2-28: Large Signal Inverting Pulse Response.

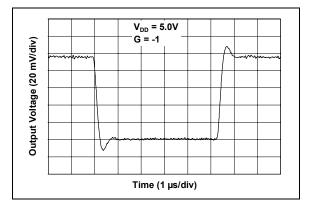


FIGURE 2-29: Small Signal Inverting Pulse Response.

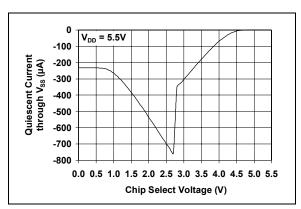


FIGURE 2-30: Quiescent Current Through V_{SS} vs. Chip Select Voltage (MCP603).

MCP601/2/3/4

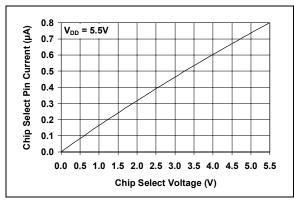


FIGURE 2-31: Chip Select Pin Input Current vs. Chip Select Voltage.

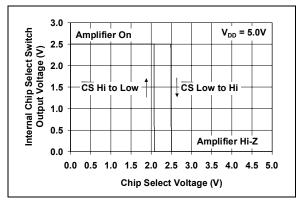


FIGURE 2-32: Hysteresis of Chip Select's Internal Switch.

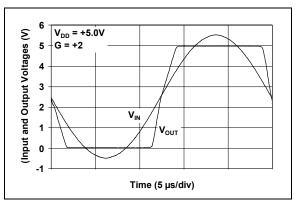


FIGURE 2-33: The MCP601/2/3/4 family of op amps shows no phase reversal under input overdrive.

3.0 APPLICATIONS INFORMATION

The MCP601/2/3/4 family of op amps are fabricated on Microchip's state-of-the-art CMOS process. They are unity-gain stable and suitable for a wide range of general purpose applications.

3.1 Input

The MCP601/2/3/4 amplifier family is designed to not exhibit phase reversal when the input pins exceed the supply rails. Figure 2-33 shows an input voltage that exceeds both supplies with no resulting phase inversion.

The Common Mode Input Voltage Range (V_{CMR}) includes ground in single-supply systems (V_{SS}), but does not include V_{DD} . This means that the amplifier input behaves linearly as long as the Common Mode Input Voltage (V_{CM}) is kept within the specified V_{CMR} limits ($V_{SS} - 0.3V$ to $V_{DD} - 1.2V$ at +25°C).

Input voltages that exceed the input voltage range ($V_{SS} - 0.3V$ to $V_{DD} - 1.2V$ at $+25^{\circ}$ C) can cause excessive current to flow into or out of the input pins. Current beyond ± 2 mA may cause reliability problems. Applications that exceed this rating must externally limit the input current with a resistor (R_{IN}), as shown in Figure 3-1.

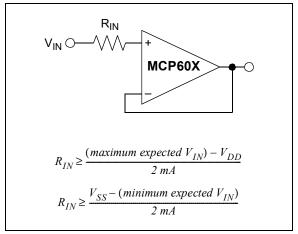


FIGURE 3-1: R_{IN} limits the current flow into an input pin.

3.2 Rail-to-Rail Output

There are two specifications that describe the output swing capability of the MCP601/2/3/4 family of op amps. The first specification (Maximum Output Voltage Swing) defines the absolute maximum swing that can be achieved under the specified load conditions. For instance, the output voltage swings to within 15 mV of the negative rail with a 25 k Ω load to V_{DD}/2. Figure 2-33 shows how the output voltage is limited when the input goes beyond the linear region of operation.

The second specification that describes the output swing capability of these amplifiers is the Linear Output Voltage Swing. This specification defines the maximum output swing that can be achieved while the amplifier is still operating in its linear region. To verify linear operation in this range, the large signal (DC Open-Loop Gain (A_{OL})) is measured at points 100 mV inside the supply rails. The measurement must exceed the specified gains in the specification table.

3.3 MCP603 Chip Select (CS)

The MCP603 is a single amplifier with Chip Select ($\overline{\text{CS}}$). When $\overline{\text{CS}}$ is pulled high, the supply current drops to -0.7 μA (typ.), which is pulled through the $\overline{\text{CS}}$ pin to V_{SS}. When this happens, the amplifier output is put into a high-impedance state. Pulling $\overline{\text{CS}}$ low enables the amplifier and, if the $\overline{\text{CS}}$ pin is left floating, the amplifier may not operate properly. Figure 1-1 is the Chip Select timing diagram and shows the output voltage, supply currents and $\overline{\text{CS}}$ current in response to a $\overline{\text{CS}}$ pulse. Figure 2-27 shows the measured output voltage response to a $\overline{\text{CS}}$ pulse.

3.4 Capacitive Loads

Driving large capacitive loads can cause stability problems for voltage feedback op amps. As the load capacitance increases, the feedback loop's phase margin decreases and the closed-loop bandwidth is reduced. This produces gain peaking in the frequency response with overshoot and ringing in the step response.

When driving large capacitive loads with these op amps (e.g., > 40 pF when G = +1), a small series resistor at the output ($R_{\rm ISO}$ in Figure 3-2) improves the feedback loop's phase margin (stability) by making the output load resistive at higher frequencies. The bandwidth will be generally lower than the bandwidth with no capacitive load.

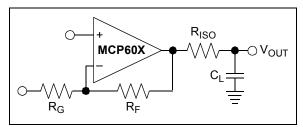


FIGURE 3-2: Output resistor R_{ISO} stabilizes large capacitive loads.

Figure 3-3 gives recommended R_{ISO} values for different capacitive loads and gains. The x-axis is the normalized load capacitance (C_L/G_N) in order to make it easier to interpret the plot for arbitrary gains. G_N is the circuit's noise gain. For non-inverting gains, G_N and the gain are equal. For inverting gains, $G_N = 1 + |Gain|$ (e.g., -1 V/V gives $G_N = 1 + |Gain|$)

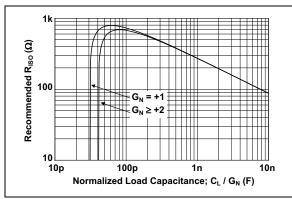


FIGURE 3-3: Recommended R_{ISO} values for capacitive loads.

Once you've selected $R_{\rm ISO}$ for your circuit, double-check the resulting frequency response peaking and step response overshoot in your circuit. Evaluation on the bench and simulations with the MCP601/2/3/4 SPICE macro model are very helpful. Modify $R_{\rm ISO}$'s value until the response is reasonable.

3.5 Supply Bypass

With this family of op amps, the power supply pin (V_{DD} for single-supply) should have a local bypass capacitor (i.e., $0.01~\mu F$ to $0.1~\mu F$) within 2 mm for good high-frequency performance. It also needs a bulk capacitor (i.e., $1~\mu F$ or larger) within 100 mm to provide large, slow currents. This bulk capacitor can be shared with other parts.

3.6 PCB Surface Leakage

In applications where low input bias current is critical, printed circuit board (PCB) surface leakage effects need to be considered. Surface leakage is caused by humidity, dust or other contamination on the board. Under low humidity conditions, a typical resistance between nearby traces is $10^{12}\Omega$. A 5V difference would cause 5 pA of current to flow. This is greater than the MCP601/2/3/4 family's bias current at +25°C (1 pA, typ.).

The easiest way to reduce surface leakage is to use a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin. An example of this type of layout is shown in Figure 3-4.

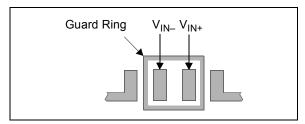


FIGURE 3-4: Example Guard Ring layout.

- Connect the guard ring to the inverting input pin (V_{IN}-) for non-inverting gain amplifiers, including unity-gain buffers. This biases the guard ring to the common mode input voltage.
- Connect the guard ring to the non-inverting input pin (V_{IN}+) for inverting gain amplifiers and transimpedance amplifiers (converts current to voltage, such as photo detectors). This biases the guard ring to the same reference voltage as the op amp (e.g., V_{DD}/2 or ground).

3.7 Typical Applications

3.7.1 ANALOG FILTERS

Figure 3-5 and Figure 3-6 show low-pass, second-order, Butterworth filters with a cutoff frequency of 10 Hz. The filter in Figure 3-5 has a non-inverting gain of +1 V/V, and the filter in Figure 3-6 has an inverting gain of -1 V/V.

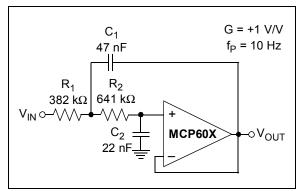


FIGURE 3-5: Second-Order, Low-Pass Sallen-Key Filter.

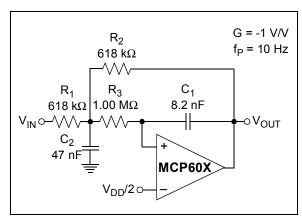


FIGURE 3-6: Second-Order, Low-Pass Multiple-Feedback Filter.

The MCP601/2/3/4 family of op amps have low input bias current, which allows the designer to select larger resistor values and smaller capacitor values for these filters. This helps produce a compact PCB layout. These filters, and others, can be designed using Microchip's FilterLab® software.

3.7.2 INSTRUMENTATION AMPLIFIER CIRCUITS

Instrumentation amplifiers have a differential input that subtracts one input voltage from another and rejects common mode signals. These amplifiers also provide a single-ended output voltage.

The three-op amp instrumentation amplifier is illustrated in Figure 3-7. One advantage of this approach is unitygain operation, while one disadvantage is that the common mode input range is reduced as R_2/R_G gets larger.

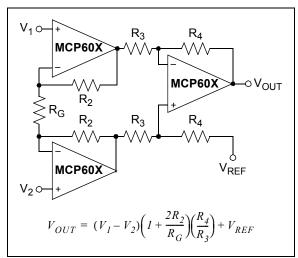


FIGURE 3-7: Three-Op Amp Instrumentation Amplifier.

The two-op amp instrumentation amplifier is shown in Figure 3-8. While its power consumption is lower than the three-op amp version, its main drawbacks are that the common mode range is reduced with higher gains and it must be configured in gains of two or higher.

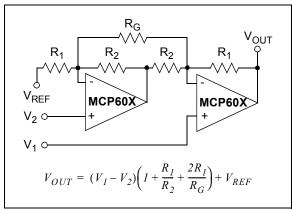


FIGURE 3-8: Two-Op Amp Instrumentation Amplifier.

Both instrumentation amplifiers should use a bulk bypass capacitor of at least 1 μ F. The CMRR of these amplifiers will be set by both the op amp CMRR and resistor matching.

3.7.3 PHOTO DETECTION

The MCP601/2/3/4 op amps can be used to easily convert the signal from a sensor that produces an output current (such as a photo diode) into a voltage (a transimpedance amplifier). This is implemented with a single resistor (R_2) in the feedback loop of the amplifiers shown in Figure 3-9 and Figure 3-10. The optional capacitor (C_2) sometimes provides stability for these circuits.

A photodiode configured in the Photovoltaic mode has zero voltage potential placed across it (Figure 3-9). In this mode, the light sensitivity and linearity is maximized, making it best suited for precision applications. The key amplifier specifications for this application are: low input bias current, low noise, common mode input voltage range (including ground) and rail-to-rail output.

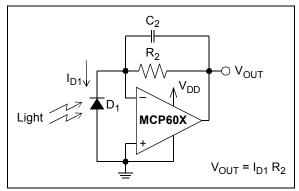


FIGURE 3-9: Photovoltaic Mode Detector.

In contrast, a photodiode that is configured in the Photoconductive mode has a reverse bias voltage across the photo-sensing element (Figure 3-10). This decreases the diode capacitance, which facilitates high-speed operation (e.g., high-speed digital communications). The design trade-off is increased diode leakage current and linearity errors. The op amp needs to have a wide Gain Bandwidth Product (GBWP).

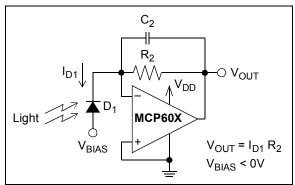


FIGURE 3-10: Photoconductive Mode Detector.

4.0 DESIGN TOOLS

Microchip provides the basic design tools needed for the MCP601/2/3/4 family of op amps.

4.1 SPICE Macro Model

The latest SPICE macro model of the MCP601/2/3/4 op amps is available on Microchip's web site at www.microchip.com. This model is intended as an initial design tool that works well in the op amp's linear region of operation at room temperature. See the SPICE model firmware for information on its capabilities.

Bench testing is a very important part of any design and cannot be replaced with simulations. Also, simulation results using this macro model need to be validated by comparing them to the data sheet specs and plots.

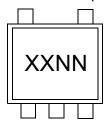
4.2 FilterLab® 2.0

FilterLab[®] 2.0 is an innovative software tool that simplifies analog active-filter (using op amps) design. Available at no cost from Microchip's web site at www.microchip.com, the FilterLab active-filter software design tool provides full schematic diagrams of the filter circuit with component values. It also outputs the filter circuit in SPICE format, which can be used with the macro model to simulate actual filter performance.

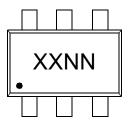
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

5-Lead SOT-23 (MCP601 and MCP601R Only)



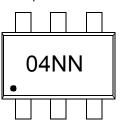
6-Lead SOT-23A (MCP603 Only)



Example:



Example:



Legend: XX...X Customer specific information*

YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

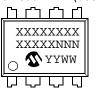
Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line thus limiting the number of available characters

for customer specific information.

* Standard OTP marking consists of Microchip part number, year code, week code, and traceability code.

Package Marking Information





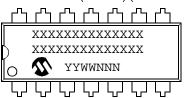
8-Lead SOIC (150 mil)



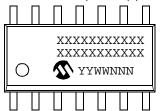
8-Lead TSSOP



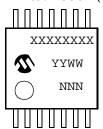
14-Lead PDIP (300 mil) (MCP604 Only)



14-Lead SOIC (150 mil) (MCP604 Only)



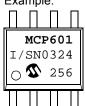
14-Lead TSSOP (4.4mm) (MCP604 Only)



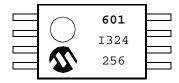
Example:



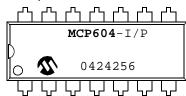
Example:



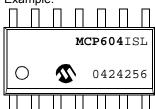
Example:



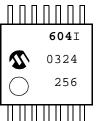
Example:



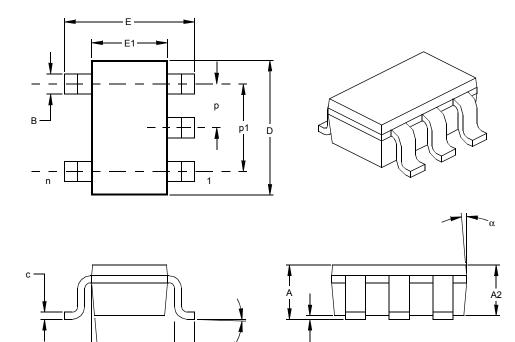
Example:



Example:



5-Lead Plastic Small Outline Transistor (OT) (SOT-23)



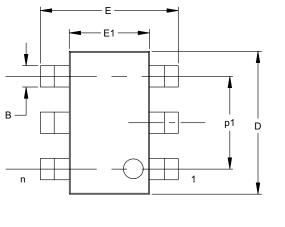
	Units	Units INCHES*				MILLIMETERS		
Dimension	on Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		5			5		
Pitch	р		.038			0.95		
Outside lead pitch (basic)	p1		.075			1.90		
Overall Height	Α	.035	.046	.057	0.90	1.18	1.45	
Molded Package Thickness	A2	.035	.043	.051	0.90	1.10	1.30	
Standoff §	A1	.000	.003	.006	0.00	0.08	0.15	
Overall Width	Е	.102	.110	.118	2.60	2.80	3.00	
Molded Package Width	E1	.059	.064	.069	1.50	1.63	1.75	
Overall Length	D	.110	.116	.122	2.80	2.95	3.10	
Foot Length	L	.014	.018	.022	0.35	0.45	0.55	
Foot Angle	ф	0	5	10	0	5	10	
Lead Thickness	С	.004	.006	.008	0.09	0.15	0.20	
Lead Width	В	.014	.017	.020	0.35	0.43	0.50	
Mold Draft Angle Top	α	0	5	10	0	5	10	
Mold Draft Angle Bottom	β	0	5	10	0	5	10	

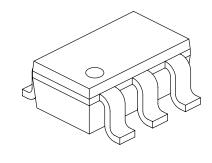
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

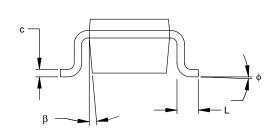
.010" (0.254mm) per side.
JEDEC Equivalent: MO-178
Drawing No. C04-091

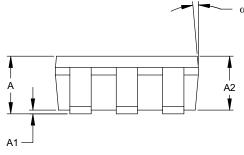
^{*} Controlling Parameter § Significant Characteristic

6-Lead Plastic Small Outline Transistor (CH) (SOT-23)









	Units	Units INCHES*				IILLIMETERS	3
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		6			6	
Pitch	р		.038			0.95	
Outside lead pitch (basic)	p1		.075			1.90	
Overall Height	Α	.035	.046	.057	0.90	1.18	1.45
Molded Package Thickness	A2	.035	.043	.051	0.90	1.10	1.30
Standoff	A1	.000	.003	.006	0.00	0.08	0.15
Overall Width	E	.102	.110	.118	2.60	2.80	3.00
Molded Package Width	E1	.059	.064	.069	1.50	1.63	1.75
Overall Length	D	.110	.116	.122	2.80	2.95	3.10
Foot Length	L	.014	.018	.022	0.35	0.45	0.55
Foot Angle	ф	0	5	10	0	5	10
Lead Thickness	С	.004	.006	.008	0.09	0.15	0.20
Lead Width	В	.014	.017	.020	0.35	0.43	0.50
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

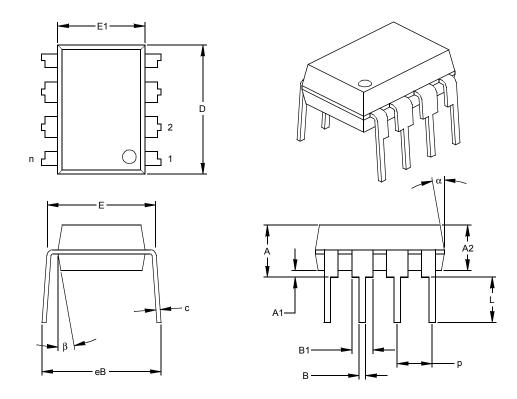
^{*}Controlling Parameter

Notes

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side.

JEITA (formerly EIAJ) equivalent: SC-74A Drawing No. C04-120

8-Lead Plastic Dual In-line (P) - 300 mil (PDIP)



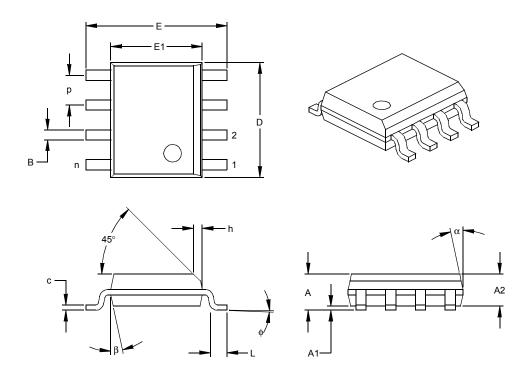
	Units		INCHES*		N	ILLIMETERS	3
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.360	.373	.385	9.14	9.46	9.78
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing §	eB	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

Notes: Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side. JEDEC Equivalent: MS-001 Drawing No. C04-018

^{*} Controlling Parameter § Significant Characteristic

8-Lead Plastic Small Outline (SN) - Narrow, 150 mil (SOIC)



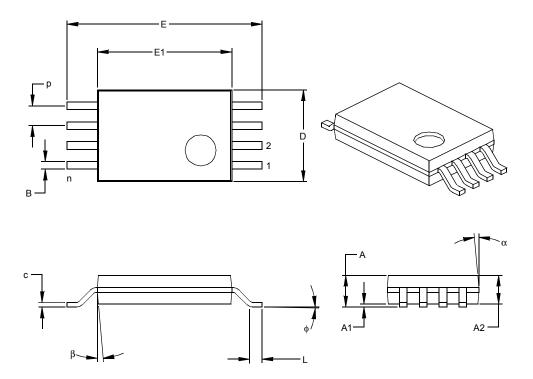
	Units		INCHES*		N	IILLIMETERS	3
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.050			1.27	
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	Е	.228	.237	.244	5.79	6.02	6.20
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99
Overall Length	D	.189	.193	.197	4.80	4.90	5.00
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.019	.025	.030	0.48	0.62	0.76
Foot Angle	ф	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.013	.017	.020	0.33	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side. JEDEC Equivalent: MS-012 Drawing No. C04-057

^{*} Controlling Parameter § Significant Characteristic

8-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm (TSSOP)



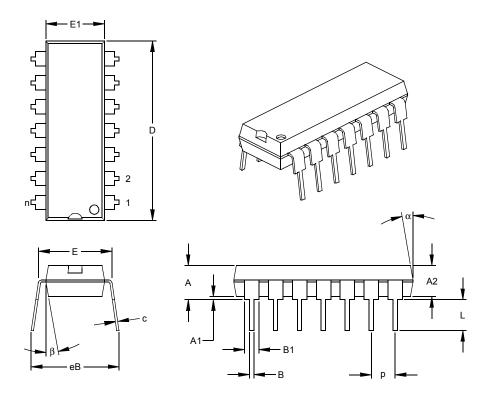
	Units		INCHES			1ILLIMETERS	S*
Dimension	n Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.026			0.65	
Overall Height	Α			.043			1.10
Molded Package Thickness	A2	.033	.035	.037	0.85	0.90	0.95
Standoff §	A1	.002	.004	.006	0.05	0.10	0.15
Overall Width	Е	.246	.251	.256	6.25	6.38	6.50
Molded Package Width	E1	.169	.173	.177	4.30	4.40	4.50
Molded Package Length	D	.114	.118	.122	2.90	3.00	3.10
Foot Length	L	.020	.024	.028	0.50	0.60	0.70
Foot Angle	ф	0	4	8	0	4	8
Lead Thickness	С	.004	.006	.008	0.09	0.15	0.20
Lead Width	В	.007	.010	.012	0.19	0.25	0.30
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.005" (0.127mm) per side. JEDEC Equivalent: MO-153 Drawing No. C04-086

^{*} Controlling Parameter § Significant Characteristic

14-Lead Plastic Dual In-line (P) - 300 mil (PDIP)

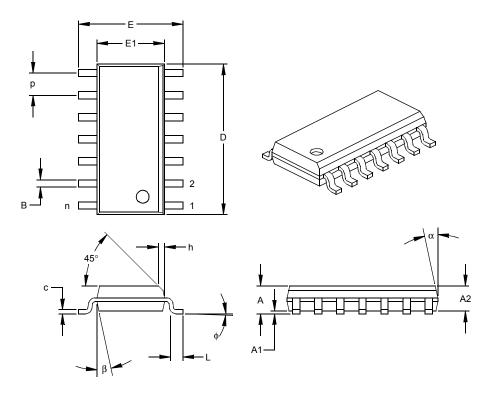


	Units		INCHES*		N	MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		14			14		
Pitch	р		.100			2.54		
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32	
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68	
Base to Seating Plane	A1	.015			0.38			
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26	
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60	
Overall Length	D	.740	.750	.760	18.80	19.05	19.30	
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43	
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38	
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78	
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56	
Overall Row Spacing §	eВ	.310	.370	.430	7.87	9.40	10.92	
Mold Draft Angle Top	α	5	10	15	5	10	15	
Mold Draft Angle Bottom	β	5	10	15	5	10	15	

Notes:
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.
JEDEC Equivalent: MS-001
Drawing No. C04-005

^{*} Controlling Parameter § Significant Characteristic

14-Lead Plastic Small Outline (SL) - Narrow, 150 mil (SOIC)



	Units	INCHES*			MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		14			14	
Pitch	р		.050			1.27	
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	E	.228	.236	.244	5.79	5.99	6.20
Molded Package Width	E1	.150	.154	.157	3.81	3.90	3.99
Overall Length	D	.337	.342	.347	8.56	8.69	8.81
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.016	.033	.050	0.41	0.84	1.27
Foot Angle	φ	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.014	.017	.020	0.36	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

Notes:

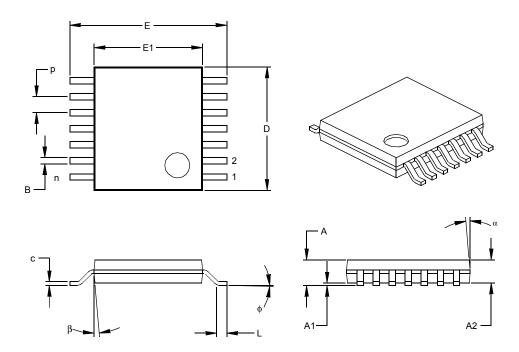
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side.

JEDEC Equivalent: MS-012 Drawing No. C04-065

^{*} Controlling Parameter § Significant Characteristic

14-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm (TSSOP)



	Units	INCHES			MILLIMETERS*		
Dimension	n Limits	MIN	MOM	MAX	MIN	NOM	MAX
Number of Pins	n		14			14	
Pitch	р		.026			0.65	
Overall Height	Α			.043			1.10
Molded Package Thickness	A2	.033	.035	.037	0.85	0.90	0.95
Standoff §	A1	.002	.004	.006	0.05	0.10	0.15
Overall Width	Е	.246	.251	.256	6.25	6.38	6.50
Molded Package Width	E1	.169	.173	.177	4.30	4.40	4.50
Molded Package Length	D	.193	.197	.201	4.90	5.00	5.10
Foot Length	L	.020	.024	.028	0.50	0.60	0.70
Foot Angle	ф	0	4	8	0	4	8
Lead Thickness	С	.004	.006	.008	0.09	0.15	0.20
Lead Width	В	.007	.010	.012	0.19	0.25	0.30
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side. JEDEC Equivalent: MO-153 Drawing No. C04-087

^{*} Controlling Parameter § Significant Characteristic

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

	order or obtain information, e.g., on pricing or delivery, refer to the factor		t_	Examples:			
PART NO.	X T	<u>/xx</u>	a)	MCP601-I/P:	Single Op Amp,		
	perature ange	Package	b)	MCP601-E/SN:	Industrial Temperature, 8LD PDIP package. Single Op Amp,		
Davidas			7		Extended Temperature, 8LD SOIC package.		
Device	MCP601 MCP601T MCP601RT	Single Op Amp Single Op Amp (Tape and Reel for SOT23, SOIC and TSSOP) Single Op Amp	(c)	MCP601T-I/OT:	Tape and Reel, Industrial Temperature, Single Op Amp, 5-LD SOT23 package.		
	MCP602 MCP602T MCP603	(Tape and Reel for SOT23-5) Dual Op Amp Dual Op Amp (Tape and Reel for SOIC and TSSOP) Single Op Amp with Chip Select	(d)	MCP601T-E/ST:	Tape and Reel, Extended Temperature, Single Op Amp, 8LD TSSOP package		
	MCP603T MCP604 MCP604T	Single Op Amp with Chip Select (Tape and Reel for SOT23, SOIC and TSSOP) Quad Op Amp Quad Op Amp	e)	MCP601RT-E/OT:	Tape and Reel, Extended Temperature, Single Op Amp, Rotated, 5-LD SOT23 package.		
Temperature Range	I = -	(Tape and Reel for SOIC and TSSOP) 40°C to +85°C	(a)	MCP602-I/SN:	Dual Op Amp, Industrial Temperature, 8LD SOIC package.		
Tomporatare Hange		40°C to +125°C	b)	MCP602-E/P:	Dual Op Amp, Extended Temperature, 8LD PDIP package.		
Package	CH = P P = P SN = P	lastic SOT23, 5-lead (MCP601 only) lastic SOT23, 6-lead (MCP603 only) lastic DIP (300 mil Body), 8, 14-lead lastic SOIC (150 mil Body), 8-lead lastic SOIC (150 mil Body), 14-lead	c)	MCP602T-E/ST:	Tape and Reel, Extended Temperature, Dual Op Amp, 8LD TSSOP package.		
		astic SOIC (150 Hill Body), 14-lead astic TSSOP (4.4mm Body), 8, 14-lead	a)	MCP603-I/SN:	Industrial Temperature, Single Op Amp with Chip Select,8LD SOIC package.		
			b)	MCP603-E/P:	Extended Temperature, Single Op Amp with Chip Select, 8LD PDIP package.		
			c)	MCP603T-E/ST:	Tape and Reel, Extended Temperature, Single Op Amp with Chip Select, 8LD TSSOP package.		
			d)	MCP603T-I/SN:	Tape and Reel, Industrial Temperature, Single Op Amp with Chip Select, 8LD SOIC package.		
			a)	MCP604-I/P:	Industrial Temperature, Quad Op Amp, 14LD PDIP package.		
			b)	MCP604-E/SL:	Extended Temperature, Quad Op Amp, 14LD SOIC package.		
			c)	MCP604T-I/ST:	Tape and Reel, Industrial Temperature, Quad Op Amp, 14LD TSSOP package.		

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Corporate Office

2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277

Technical Support: 480-792-7627 Web Address: http://www.microchip.com

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3780 Mansell Road, Suite 130 Alpharetta, GA 30022 Tel: 770-640-0034 Fax: 770-640-0307

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Fax: 61-2-9868-6755

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Netherlands P. A. De Biesbosch 14

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